

original #12/c
DOCKET NO: 214183US2

RESPONSE UNDER 37 CFR 1.116-
EXPEDITED PROCEDURE EXAMINING
GROUP 2826

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

Yoshihiro MINAMI

: EXAMINER: MANDALA, V. A.

SERIAL NO: 09/960,333

: GROUP ART UNIT: 2826

FILED: SEPTEMBER 24, 2001

:

FOR: SEMICONDUCTOR DEVICE WITH
SPIRAL INDUCTOR AND METHOD
FOR FABRICATING
SEMICONDUCTOR INTEGRATED
CIRCUIT DEVICE

RECEIVED
APR 30 2003
TECHNOLOGY CENTER 2800

AMENDMENT UNDER 37 C.F.R. § 1.116

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

In response to the Office Action dated January 30, 2003, please amend the above-identified application as follows:

IN THE CLAIMS

Please amend Claims 1, 5, 7, 10, and 12 as shown in clean form below:¹

1. (Thrice Amended) A semiconductor device comprising:

62 61
62 a substrate
FC:1202 65/32000 GLEN
a protruding portion which is formed on the top face of the substrate; and
a conductive layer wiring which is formed on the substrate so as to have a spiral shape
and which serves as an induction element,

¹ A marked-up copy of the amendments is attached hereto.

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